# MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet

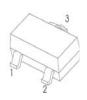


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**SOT - 23** 



- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

#### TRANSISTOR (NPN)

#### **FEATURES**

- High breakdown voltage
- Low collector-emitter saturation voltage
- Complementary to MMBTA92-MS (PNP)

Marking: 1D

#### MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	300	V
V <sub>CEO</sub>	Collector-Emitter Voltage	300	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current -Continuous	0.3	Α
I <sub>CM</sub>	Collector Current-Peak	0.5	А
Pc	Collector Power dissipation	0.35	W
R <sub>OJA</sub>	Thermal Resistance, junction to Ambient	357	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	${\mathbb C}$

#### **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

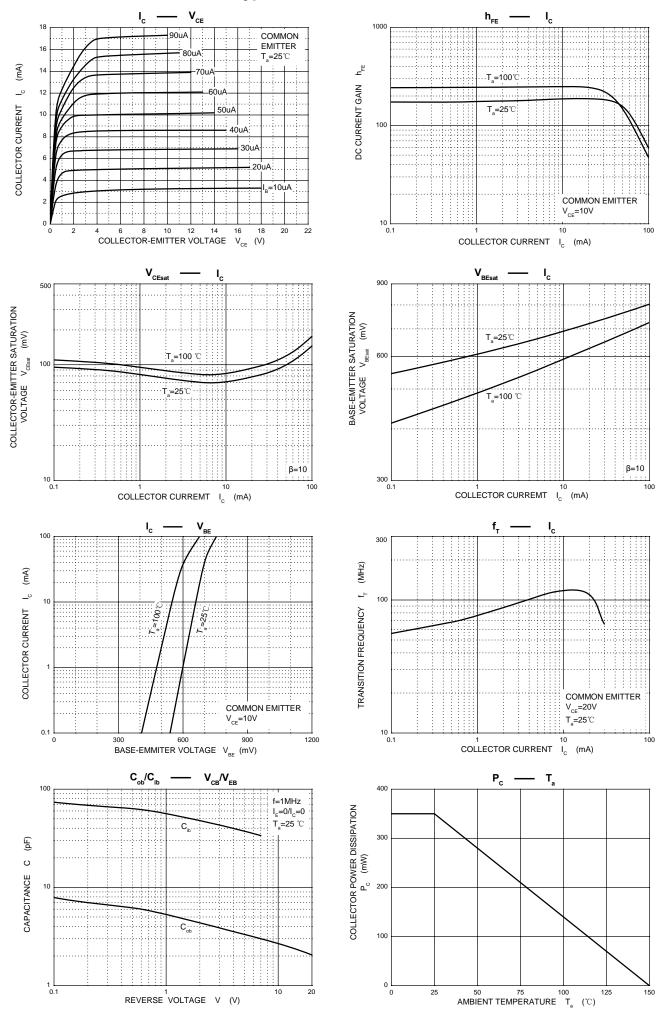
Parameter	Symbol	Test conditions	Min	Max	Unit		
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μΑ,I <sub>E</sub> =0	300		V		
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 1mA, I <sub>B</sub> =0	300		V		
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 100μA, I <sub>C</sub> =0	5		٧		
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =200V, I <sub>E</sub> =0		0.25	μΑ		
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ = 5V, $I_{C}$ =0		0.1	μA		
	h <sub>FE(1)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA	60				
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> =10mA	100	200			
	h <sub>FE(3)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =30mA	60				
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =20mA, I <sub>B</sub> = 2mA		0.2	V		
Base-emitter saturation voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = 20mA, I <sub>B</sub> =2mA		0.9	V		
Transition frequency	f⊤	V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA,	50		MHz		
Transition frequency		f=30MHz	30		1411 12		



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#### Compiance

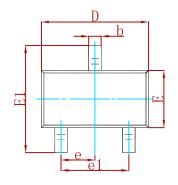
### **Typical Characteristics**

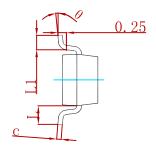


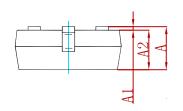


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#### **PACKAGE MECHANICAL DATA**

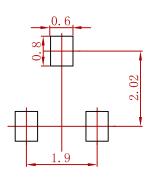






Cumhal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950	) TYP	0.037	7 TYP
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
MMBTA42-MS	SOT-23	3000



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